

DATA SHEET

CBTD16213

24-bit level shifting bus exchange switch
with 12-bit output enables

Product data

2001 Nov 08

File under Integrated Circuits — ICL03

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CBTD16213

FEATURES

- 5 Ω switch connection between two ports
- TTL compatible control input levels
- Designed to be used in level shifting applications
- Package options include plastic shrink small outline (SSOP) and thin shrink small outline (TSSOP)
- Latch-up testing is done to JESDEC Standard JESD78 which exceeds 100 mA
- ESD protection exceeds 1500 V HBM per JESD22-114A and 1000 V CDM per JESD22-C101

DESCRIPTION

The CBTD16213 provides 24 bits of high-speed TTL-compatible bus switching or exchanging. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

A diode to V_{CC} is integrated into the circuit to allow for level shifting between 5 V inputs and 3.3 V outputs.

The CBTD16213 operates as 24-bit bus switch or a 12-bit bus exchanger, which provides data exchanging between the four signal ports via the data-select (S_0 – S_2) terminals.

The CBTD16213 is characterized for operation from -40 to $+85$ $^{\circ}\text{C}$.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{\text{amb}} = 25$ $^{\circ}\text{C}$; $\text{GND} = 0$ V	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay An to Yn	$C_L = 50$ pF; $V_{CC} = 5$ V	0.25	ns
C_{IN}	Input capacitance	$V_I = 0$ V or V_{CC}	4.5	pF
C_{OUT}	Output capacitance	Outputs disabled; $V_O = 0$ V or V_{CC}	11.5	pF
I_{CC}	Total supply current	Outputs disabled; $V_{CC} = 5.5$ V	1.5	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER
56-Pin Plastic SSOP	-40 to $+85$ $^{\circ}\text{C}$	CBTD16213DL	SOT371-1
56-Pin Plastic TSSOP	-40 to $+85$ $^{\circ}\text{C}$	CBTD16213DGG	SOT364-1

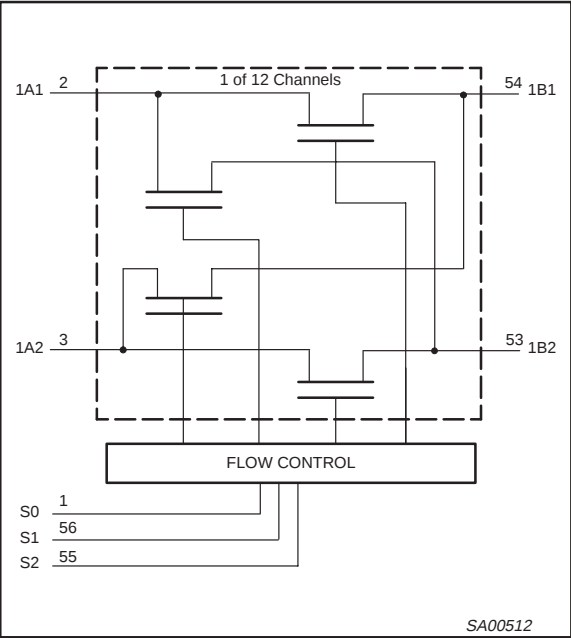
Standard packing quantities and other packaging data is available at www.philipslogic.com/packaging.

FUNCTION TABLE

S2	S1	S0	A1	A2	FUNCTION
L	L	L	Z	Z	Disconnect
L	L	H	B1	Z	$A1 = B1$
L	H	L	B2	Z	$A1 = B2$
L	H	H	Z	B1	$A2 = B1$
H	L	L	Z	B2	$A2 = B2$
H	L	H	$A2 \& B2$	$A1 \& B2$	$A1 = A2 = B2$
H	H	L	B1	B2	$A1 = B1, A2 = B2$
H	H	H	B2	B1	$A1 = B2, A2 = B1$

H = High voltage level
L = Low voltage level
Z = High impedance "off" state

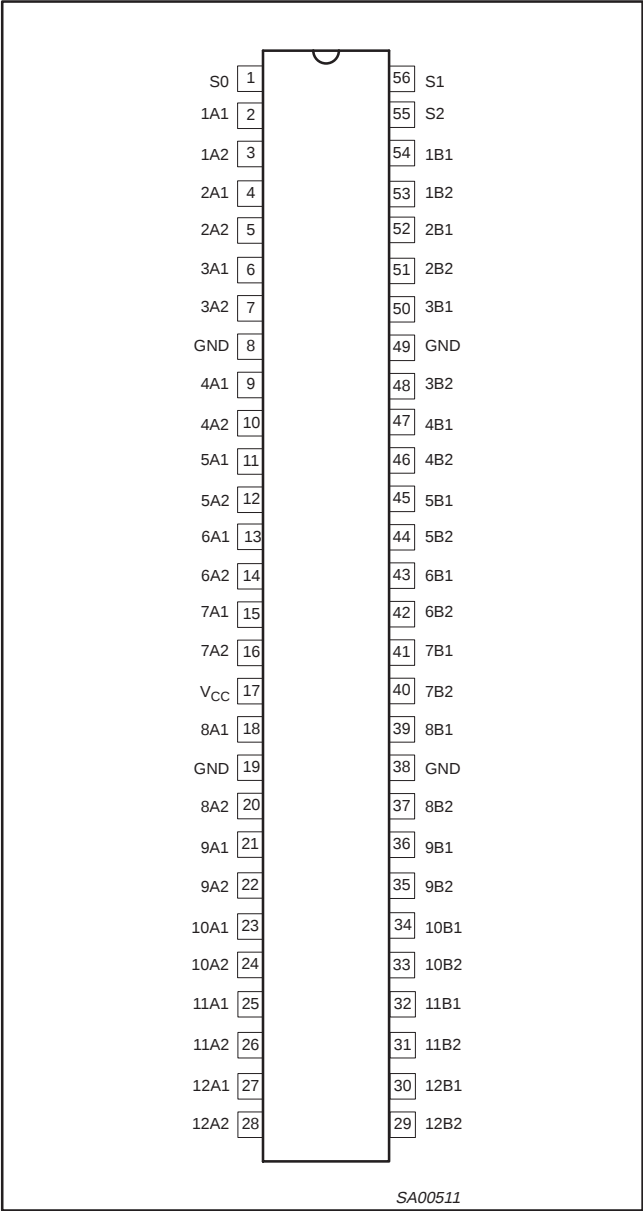
LOGIC SYMBOL



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PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 56, 55	S0, S1, S2	Data select
2, 4, 6, 9, 11, 13, 15, 18, 21, 23, 25, 27	1A1–12A1	A1 channel
3, 5, 7, 10, 12, 14, 16, 20, 22, 24, 26, 28	1A2–12A2	A2 channel
54, 52, 50, 47, 45, 43, 41, 39, 36, 34, 32, 30	1B1, 12B1	B1 channel
53, 51, 48, 46, 44, 42, 40, 37, 35, 33, 31, 29	1B2, 12B2	B2 channel
8, 19, 38, 49	GND	Ground (0 V)
17	V _{CC}	Positive supply voltage

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		−0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0	−50	mA
V _I	DC input voltage ³		−0.5 to +7.0	V
V _{OUT}	DC output voltage ³	output in Off or High state	−0.5 to +5.5	V
I _{OUT}	DC output current	output in Low state	128	mA
T _{stg}	Storage temperature range		−65 to +150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		Min	Max	
V _{CC}	DC supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2.0	—	V
V _{IL}	Low-level Input voltage	—	0.8	V
T _{amb}	Operating free-air temperature range	−40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			T _{amb} = −40 to +85 °C			
			Min	Typ ¹	Max	
V _{IK}	Input clamp voltage	V _{CC} = 4.5 V; I _I = −18 mA	—	—	−1.2	V
V _P	Output high pass voltage	See Figure 1.	—	—	—	V
I _I	Input leakage current	V _{CC} = 0 V; V _I = 5.5 V	—	—	10	μA
		V _{CC} = 5.5 V; V _I = GND or 5.5 V	—	—	±1	
I _{CC}	Quiescent supply current	V _{CC} = 5.5 V; I _O = 0, V _I = V _{CC} or GND	—	—	1.5	mA
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 5.5 V, one input at 2.7 V, other inputs at V _{CC} or GND	—	—	2.5	mA
C _I	Control pins	V _I = 3 V or 0 V	—	4.5	—	pF
C _{IO(OFF)}	Port off capacitance B port	V _O = 3 V or 0 V; S ₀ , S ₁ , or S ₂ = V _{CC}	—	11.5	—	pF
	Port off capacitance A port		—	11.5	—	pF
r _{on} ³	A to B or B to A	V _{CC} = 4.5 V; V ₁ = 0 V; I _I = 64 mA	—	4	8	Ω
		V _{CC} = 4.5 V; V ₁ = 0 V; I _I = 30 mA	—	4	8	
		V _{CC} = 4.5 V; V ₁ = 2.4 V; I _I = 15 mA	—	15	20	
	A1 to A2	V _{CC} = 4.5 V; V ₁ = 0 V; I _I = 64 mA	—	8	10	
		V _{CC} = 4.5 V; V ₁ = 0 V; I _I = 30 mA	—	8	10	
		V _{CC} = 4.5 V; V ₁ = 2.4 V; I _I = 15 mA	—	24	30	

NOTES:

1. All typical values are at $V_{CC} = 5 \text{ V}$, $T_{amb} = 25 \text{ }^{\circ}\text{C}$
2. This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.
3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch.
On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

AC CHARACTERISTICS

GND = 0 V; t_R ; $C_L = 50 \text{ pF}$

SYMBOL	PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = +5.0 \text{ V} \pm 0.5 \text{ V}$		UNIT
				Min	Max	
t_{pd}	Propagation delay ¹	A or B	B or A	—	0.25	ns
		A1	A2	—	0.5	ns
t_{en}	Output enable time to High and Low level	S	A or B	3.2	9.6	ns
		S0	A2 and B2	1.8	8.2	ns
t_{dis}	Output disable time from High and Low level	S	A or B	2.1	8.5	ns
		S0	A2 and B2	1.4	7.5	ns

NOTES:

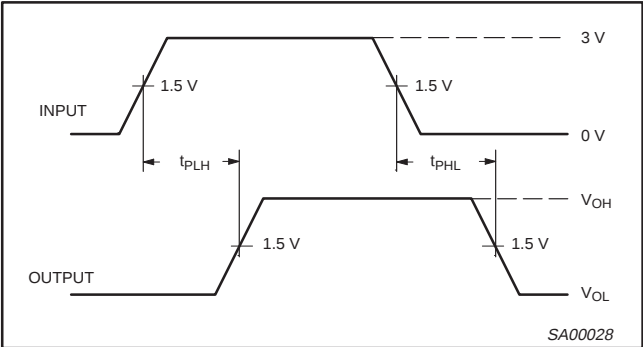
1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

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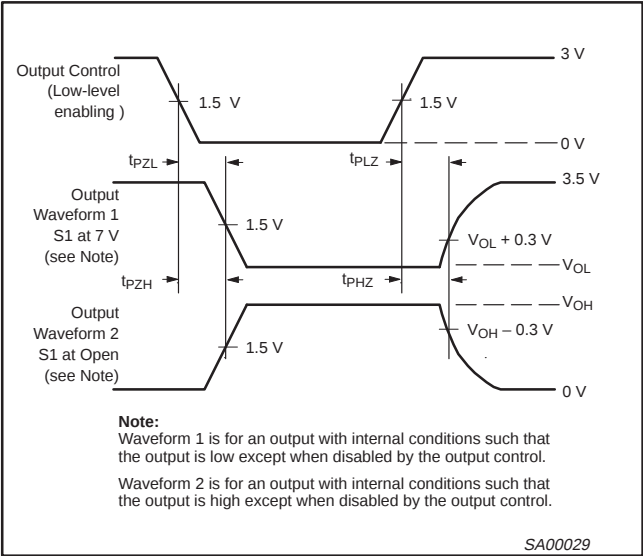
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AC WAVEFORMS

$V_M = 1.5\text{ V}$, $V_{IN} = \text{GND to } 3.0\text{ V}$

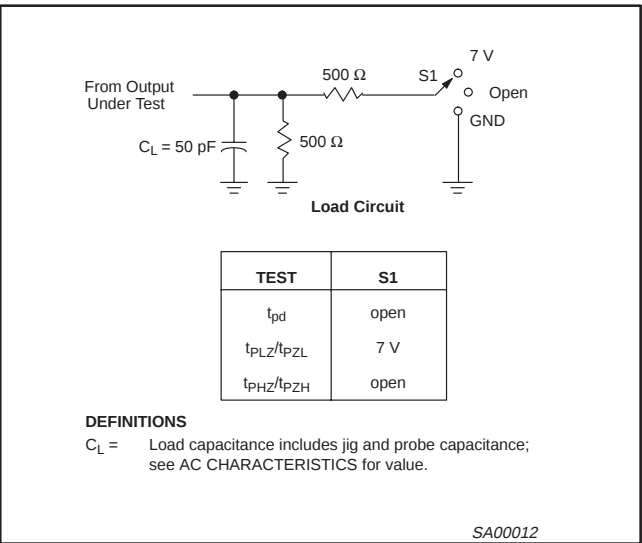


Waveform 1. Input (An) to Output (Yn) Propagation Delays



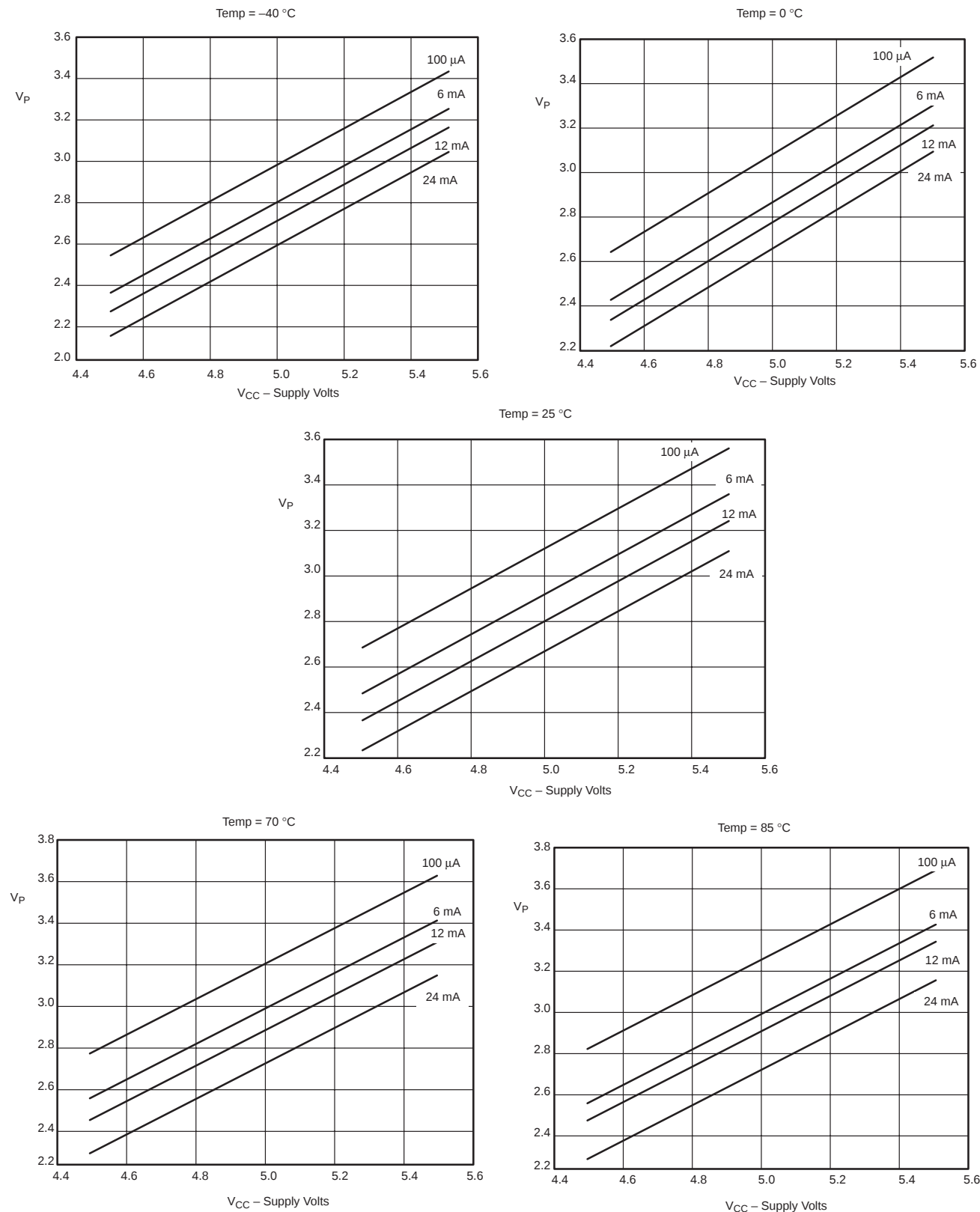
Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



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SW00840

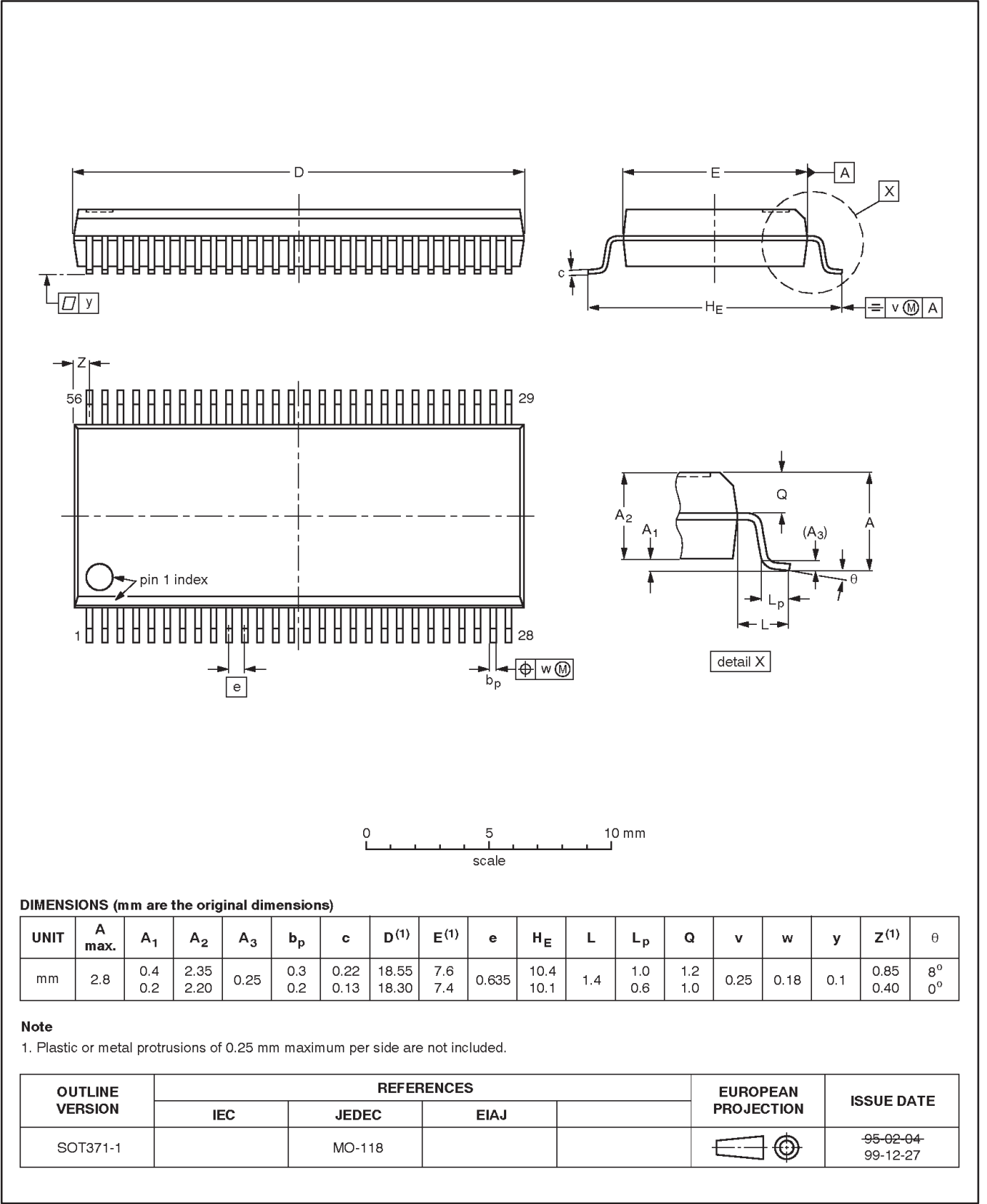
Figure 1. Typical characteristics

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SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1

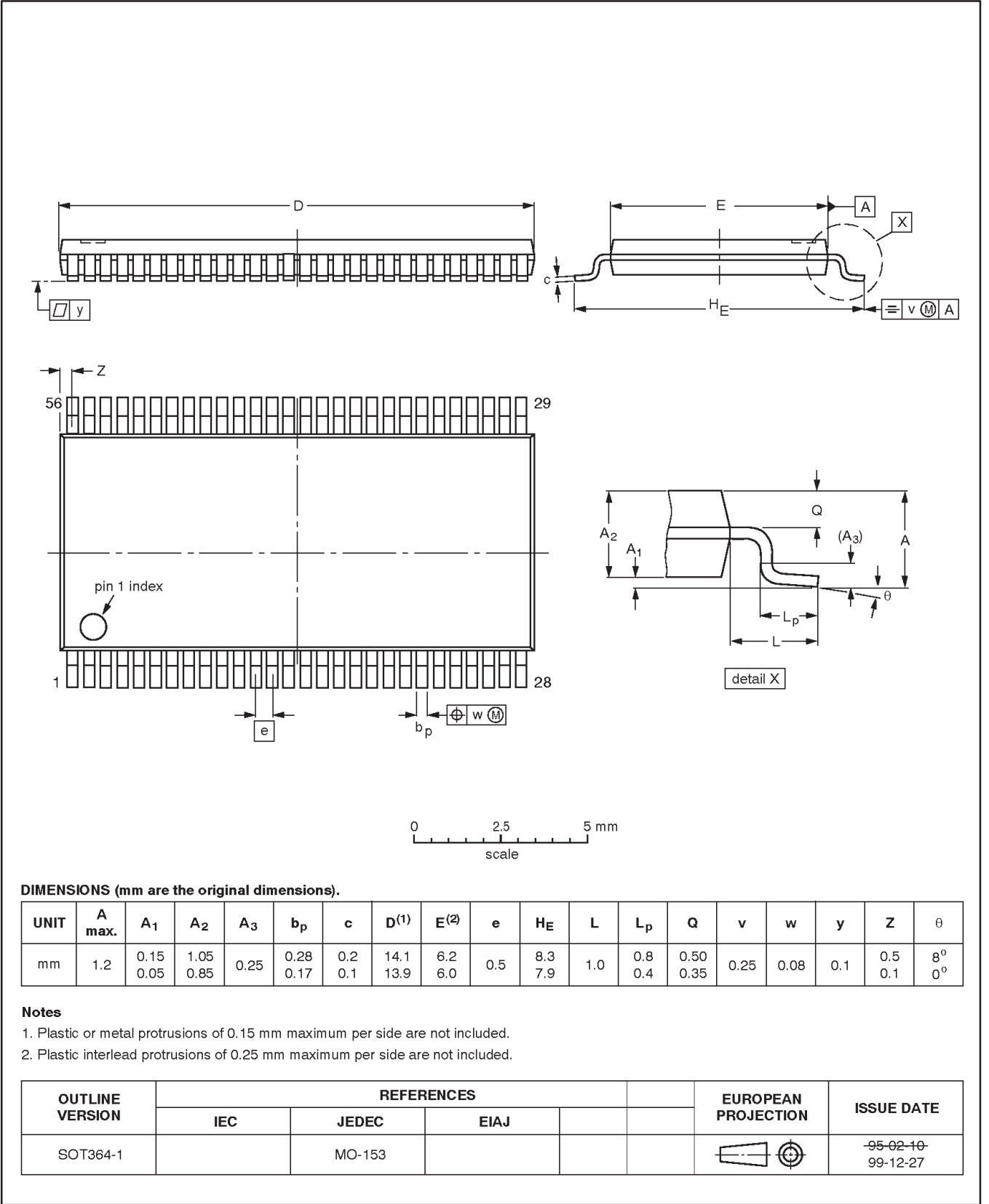


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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1 mm

SOT364-1



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Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

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